NSN 5962-01-058-2686

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range: -65.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius Features Provided: Bipolar and compatible dtl and high speed Inclosure Material: Plastic Inclosure Configuration:
-65.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius Features Provided: Bipolar and compatible dtl and high speed Inclosure Material: Plastic
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Inclosure Material: Plastic
Plastic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
11 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Memory Device Type:
Rom
Terminal Type And Quantity:
14 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A458a0